

Electrical Characteristics @ Tj = 25°C (Unless Otherwise Specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
BV _{DSS}	Drain-to-Source Breakdown Voltage	100			V	$V_{GS} = 0V, I_{D} = 1.0mA$	
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient		0.1		V/°C	Reference to 25°C, I _D = 1.0mA	
R _{DS(on)}	Static Drain-to-Source On-Resistance			0.077	Ω	V _{GS} = 10V, I _{D2} = 16A ④	
$V_{GS(th)}$	Gate Threshold Voltage	2.0		4.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Gfs	Forward Transconductance	9.1			S	V _{DS} = 15V, I _{D2} = 16A ④	
I _{DSS}	Zero Gate Voltage Drain Current			25		$V_{DS} = 80V, V_{GS} = 0V$	
				250	μA	$V_{DS} = 80V, V_{GS} = 0V, T_{J} = 125^{\circ}C$	
I _{GSS}	Gate-to-Source Leakage Forward			100	nA	$V_{GS} = 20V$	
	Gate-to-Source Leakage Reverse			-100	ш	V _{GS} = -20V	
Q_G	Total Gate Charge			59		I _{D1} = 16A	
Q_{GS}	Gate-to-Source Charge			12	nC	V _{DS} = 50V	
Q_{GD}	Gate-to-Drain ('Miller') Charge			30.7		V _{GS} = 10V	
t _{d(on)}	Turn-On Delay Time			21		V _{DD} = 50V	
tr	Rise Time			145	ne	$I_{D1} = 16A$ $R_G = 9.1\Omega$	
t _{d(off)}	Turn-Off Delay Time			64	ns		
t _f	Fall Time			105		V _{GS} = 10V	
Ls +L _D	Total Inductance		6.8		nH	Measured from drain lead (6mm/0.25in. from package) to source lead (6mm/0.25in. from package)	
C _{iss}	Input Capacitance		1660			$V_{GS} = 0V$ $V_{DS} = 25V$	
Coss	Output Capacitance		550		pF		
C _{rss}	Reverse Transfer Capacitance		120			f = 1.0MHz	

Source-Drain Diode Ratings and Characteristics

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
I _S	Continuous Source Current (Body Diode)			16	۸		
I _{SM}	Pulsed Source Current (Body Diode) ①			100	Α		
V_{SD}	Diode Forward Voltage			1.5	V	$T_J = 25^{\circ}C, I_S = 16A, V_{GS} = 0V$	
t _{rr}	Reverse Recovery Time			400	ns	$T_J = 25^{\circ}C, I_F = 16A, V_{DD} \le 50V$	
Q _{rr}	Reverse Recovery Charge			2.4	μC	di/dt = 100A/µs ④	
Ton	Forward Turn-On Time	Intrinsic turn-on time is negligible (turn-on is dominated by L _S +L _D)					

Thermal Resistance

Symbol	Parameter	Min.	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case			1.25	
$R_{\theta CS}$	Case-to-sink		0.21		°C/W
$R_{\theta JA}$	Junction-to-Ambient (Typical Socket Mount)			80	

Footnotes:

- ① Repetitive Rating; Pulse width limited by maximum junction temperature.
- $^{\circ}$ V_{DD} = 25V, starting T_J = 25°C, L = 1.8mH, Peak I_L = 16A, V_{GS} = 10V.
- $\label{eq:local_sd} \mbox{\Im} \quad I_{SD} \ \leq 16A, \ di/dt \ \leq \ 170A/\mu s, \ V_{DD} \leq 100V, \ T_J \leq 150^{\circ}C.$

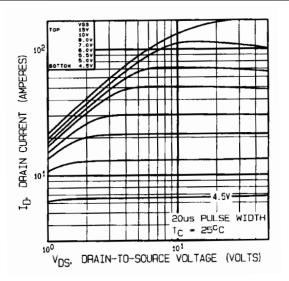


Fig 1. Typical Output Characteristics

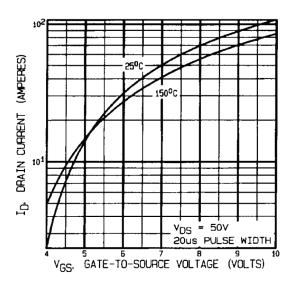


Fig 3. Typical Transfer Characteristics

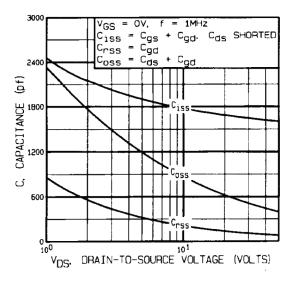


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

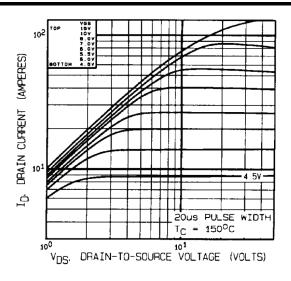


Fig 2. Typical Output Characteristics

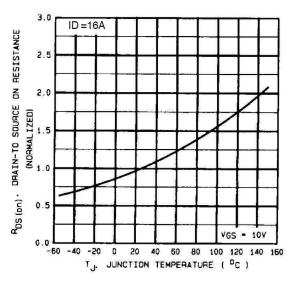


Fig 4. Normalized On-Resistance Vs. Temperature

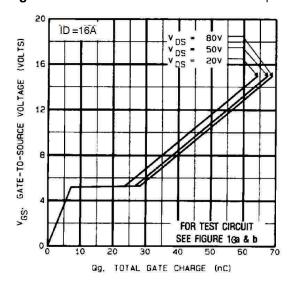


Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage

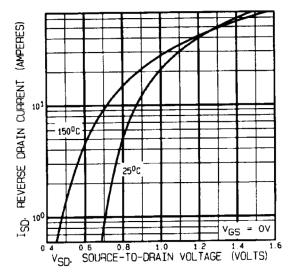


Fig 7. Typical Source-Drain Diode Forward Voltage

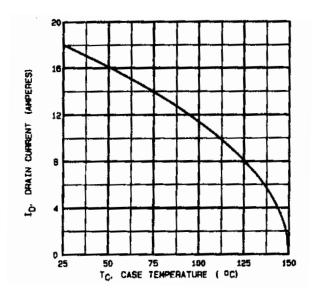


Fig 9. Maximum Drain Current Vs.Case Temperature

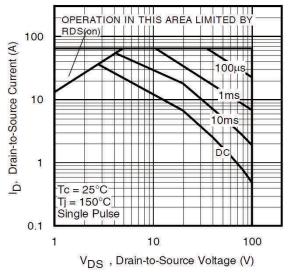


Fig 8. Maximum Safe Operating Area

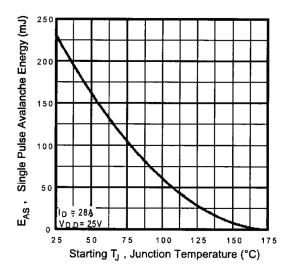


Fig 10. Maximum Avalanche Energy Vs. Drain Current

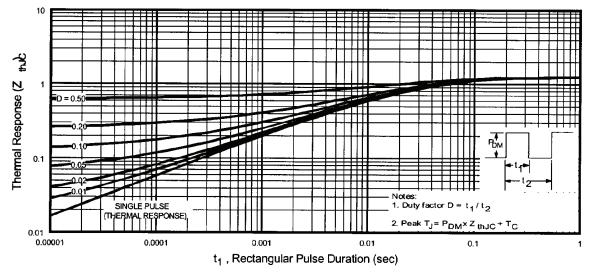


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case

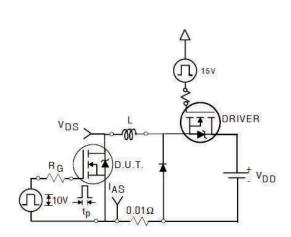


Fig 12a. Unclamped Inductive Test Circuit

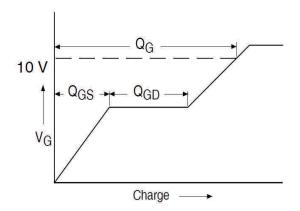


Fig 13a. Gate Charge Waveform

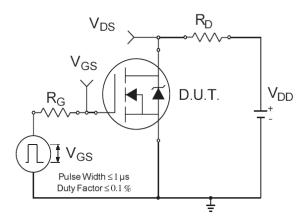


Fig 14a. Switching Time Test Circuit

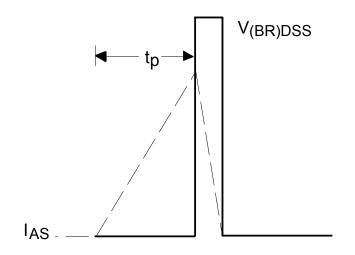


Fig 12b. Unclamped Inductive Waveforms

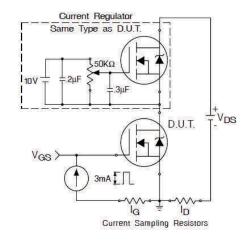


Fig 13b. Gate Charge Test Circuit

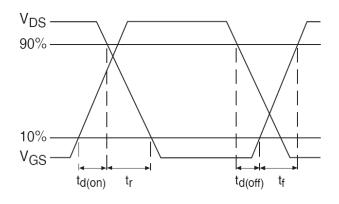
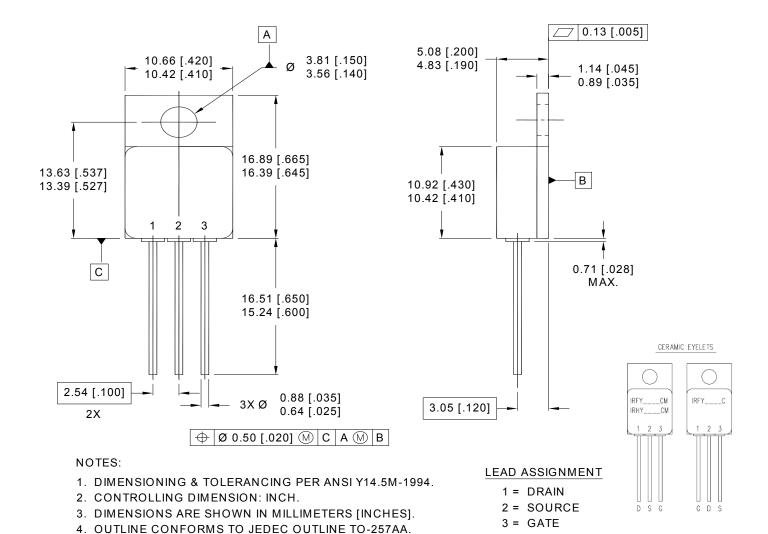


Fig 14b. Switching Time Waveforms



Case Outline and Dimensions - TO257AA





www.infineon.com/irhirel

Infineon Technologies Service Center: USA Tel: +1 (866) 951-9519 and International Tel: +49 89 234 65555

Leominster, Massachusetts 01453, USA Tel: +1 (978) 534-5776

San Jose, California 95134, USA Tel: +1 (408) 434-5000

Data and specifications subject to change without notice.



IMPORTANT NOTICE

The information given in this document shall be in no event regarded as guarantee of conditions or characteristic. The data contained herein is a characterization of the component based on internal standards and is intended to demonstrate and provide guidance for typical part performance. It will require further evaluation, qualification and analysis to determine suitability in the application environment to confirm compliance to your system requirements.

With respect to any example hints or any typical values stated herein and/or any information regarding the application of the product, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind including without limitation warranties on non- infringement of intellectual property rights and any third party.

In addition, any information given in this document is subject to customer's compliance with its obligations stated in this document and any applicable legal requirements, norms and standards concerning customer's product and any use of the product of Infineon Technologies in customer's applications.

The data contained in this document is exclusively intended for technically trained staff. It is the responsibility of any customer's technical departments to evaluate the suitability of the product for the intended applications and the completeness of the product information given in this document with respect to applications.

For further information on the product, technology, delivery terms and conditions and prices, please contact your local sales representative or go to (www.infineon.com/hirel).

WARNING

Due to technical requirements products may contain dangerous substances. For information on the types in question, please contact your nearest Infineon Technologies office.